UCF-293DIV

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I THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant

CHOW ET AL

Serial No.

10/764,242

Filed

01/23/2004

TC/A.U.

2832

Examiner

Karl D. Eastholm

Docket No.

UCF-293DIV

Customer No.

23717

For

NANO SCALE TEMPERATURE SENSORS AND HEATERS

Commissioner of Patents and Trademarks

P.O. Box 1450

Alexandria, VA 22313-1450

MAILED:

Honorable Commissioner:

I enclose the following papers:

1. Amendment Response and Arguments

Please enter the above correspondence.

Respectfully submitted,

Brian S. Steinberger Attorney at Law

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CERTIFICATE OF MAILING (37 CFR 1.8a)

I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being deposited with the United States Postal Service on the date shown below as First Class Mail, in an envelope addressed to the: Commissioner of Patents and Trademarks, P.O. Box 1450 Alexandria, VA 22313-1450.

Brian S. Steinberger (Name of Person Mailing Attached Papers)

(Signature of Person Mailing Attached Papers)

Appl No.: 10/764,242

Atty. Dkt. UCF-293DIV

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AMENDMENT

Sir:

In response to the office action mailed March 16, 2005, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims, which begins on page 3 of this paper.

Remarks/Arguments begin on page 6 of this paper.

Appl No.: 10/764,242 Atty. Dkt. UCF-293DIV

This paragraph change will replace all prior versions, and listings, in the application.

Page 2, line 25, add paragraphs as follows:

In preferred embodiments, the first metal nano sized strip and the second metal nano sized strip each can include a thickness(diameter) of approximately 50nm, and a bimetal sensing junction therebetween that can include a cross-sectional area of approximately 50 X 50 nm².

Further objects and advantages of this invention will be apparent from the following detailed description of the presently preferred embodiments which are illustrated schematically in the accompanying drawings.